MOSFETs Silicon N-Channel MOS

SSM3H137TU

1. Applications

- Relay Drivers

2. Features

(1) AEC-Q101 (Rev. D) qualified. (Note 1)

(2) 4.0-V gate drive voltage.

(3) Low drain-source on-resistance

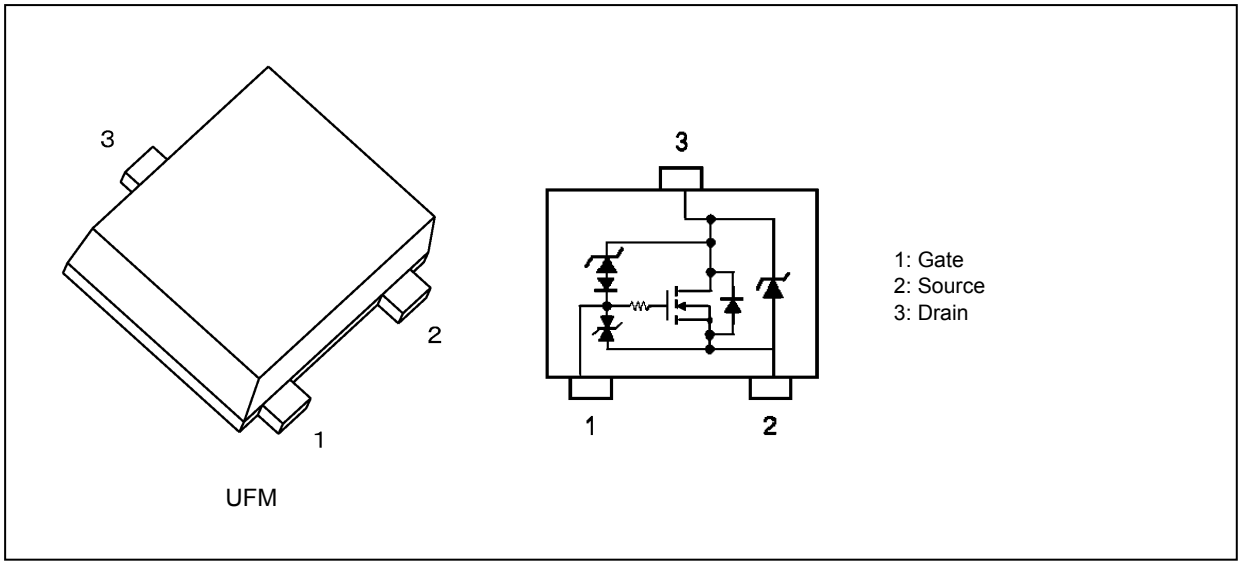
: $R_{DS(ON)}$ = 295 mΩ (max) (@V_{GS} = 4.0 V, I_D = 0.5 A)

$R_{DS(ON)}$ = 280 mΩ (max) (@V_{GS} = 4.5 V, I_D = 1.0 A)

$R_{DS(ON)}$ = 240 mΩ (max) (@V_{GS} = 10 V, I_D = 1.0 A)

Note 1: For detail information, Please contact to our sales.

3. Packaging and Pin Assignment



Start of commercial production

2016-03

4. Absolute Maximum Ratings (Note) (Unless otherwise specified, T_a = 25 °C)

Characteristics			Symbol	Rating	Unit
Drain-source voltage			V_{DSS}	34	V
Gate-source voltage			V_{GSS}	±20	
Drain current (DC)		(Note 1)	I_D	2	A
Drain current (pulsed)		(Note 1), (Note 2)	I_{DP}	6	
Power dissipation		(Note 3)	P_D	800	mW
Power dissipation	(t = 1 s)	(Note 3)		1000	
Channel temperature			T_{ch}	150	°C
Single-pulse avalanche energy		(Note 4)	E_{AS}	3.5	mJ
Avalanche current			I_{AR}	2.0	A
Storage temperature			T_{stg}	-55 to 150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Ensure that the channel temperature does not exceed 150 °C.

Note 2: Pulse width (PW) ≤ 10 μs, duty ≤ 1%

Note 3: Device mounted on an FR4 board. (25.4 mm × 25.4 mm × 1.6 mm ,Cu pad: 645 mm^2)

Note 4: V_{DD} = 25 V, Starting T_{ch} = 25 °C, L = 0.5 mH

Note: The MOSFETs in this device are sensitive to electrostatic discharge. When handling this device, the worktables, operators, soldering irons and other objects should be protected against anti-static discharge.

Note: The channel-to-ambient thermal resistance, $R_{th(ch-a)}$, and the drain power dissipation, P_D, vary according to the board material, board area, board thickness and pad area. When using this device, be sure to take heat dissipation fully into account.

5. Electrical Characteristics

5.1. Static Characteristics (Unless otherwise specified, T_a = 25 °C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Drain-source breakdown voltage		$V_{(BR)DSS}$	I_D = 1 mA, V_{GS} = 0 V	34	—	37	V
Drain cut-off current		I_{DSS}	V_{DS} = 30.4 V, V_{GS} = 0V	—	—	10	μA
Gate leakage current		I_{GSS}	V_{GS} = ±16 V, V_{DS} = 0V	—	—	±10	
Gate threshold voltage	(Note 1)	V_{th}	V_{DS} = 10 V, I_D = 1 mA	0.7	—	1.7	V
Drain-source on-resistance	(Note 2)	$R_{DS(ON)}$	V_{GS} = 4.0 V, I_D = 0.5 A	—	230	295	mΩ
			V_{GS} = 4.5 V, I_D = 1.0 A	—	220	280	
			V_{GS} = 10 V, I_D = 1.0 A	—	200	240	
Forward transfer admittance	(Note 2)	$\|Y_{fs}\|$	V_{DS} = 10 V, I_D = 0.5 A	—	2.2	—	S

Note 1: Let V_{th} be the voltage applied between gate and source that causes the drain current (I_D) to below (1 mA for this device). Then, for normal switching operation, $V_{GS(ON)}$ must be higher than V_{th}, and $V_{GS(OFF)}$ must be lower than V_{th}. This relationship can be expressed as: $V_{GS(OFF)} < V_{th} < V_{GS(ON)}$.
Take this into consideration when using the device.

Note 2: Pulse measurement.

5.2. Dynamic Characteristics (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Input capacitance	C_{iss}	V_{DS} = 10 V, V_{GS} = 0 V, f = 1 MHz	—	119	—	pF
Reverse transfer capacitance	C_{rss}		—	8	—	
Output capacitance	C_{oss}		—	40	—	
Switching time (turn-on time)	t_{on}	V_{DD} = 20 V, I_D = 0.5 A, V_{GS} = 0 to 4.5 V, R_G = 10 Ω Duty ≤ 1%, V_{IN}: t_r, t_f < 5 ns, Common source, See Chapter 5.3.	—	320	—	ns
Switching time (turn-off time)	t_{off}		—	800	—	

5.3. Switching Time Test Circuit

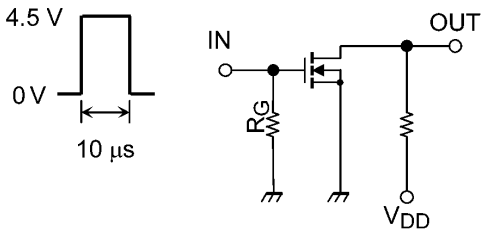


Fig. 5.3.1 Switching Time Test Circuit

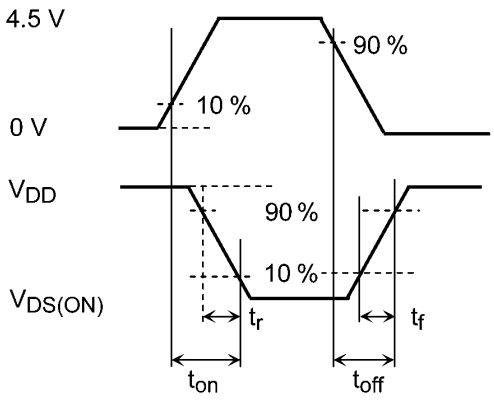


Fig. 5.3.2 Input Waveform/Output Waveform

5.4. Gate Charge Characteristics (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Q_g	V_{DD} = 20 V, I_D = 1.0 A, V_{GS} = 10 V	—	3.0	—	nC
Gate-source charge 1	Q_{gs1}		—	0.8	—	
Gate-drain charge	Q_{gd}		—	0.4	—	

5.5. Source-Drain Characteristics (Unless otherwise specified, T_a = 25 °C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Diode forward voltage	(Note 1)	V_{DSF}	I_D = -2.0 A, V_{GS} = 0 V	—	-0.82	-1.2	V

Note 1: Pulse measurement.

6. Marking

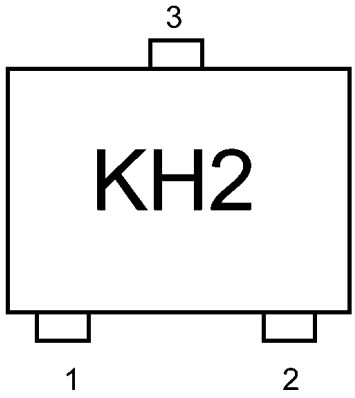


Fig. 6.1 Marking

7. Characteristics Curves (Note)

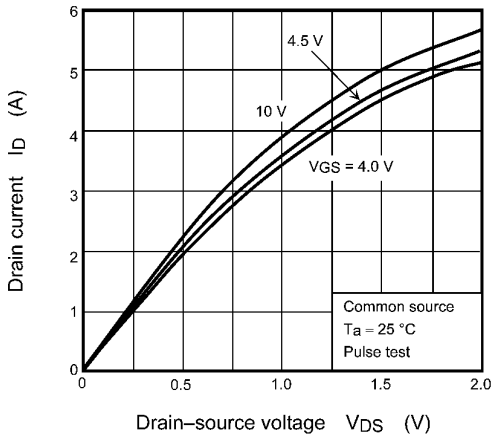


Fig. 7.1 I_D - V_{DS}

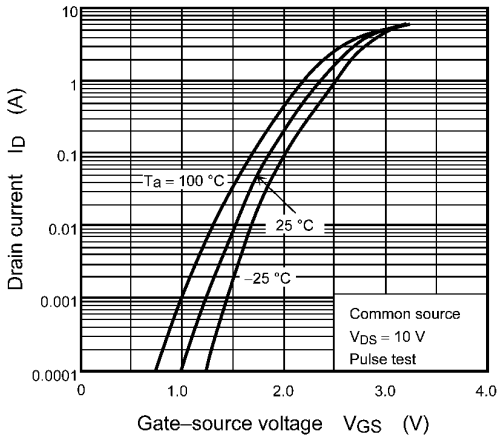


Fig. 7.2 I_D - V_{GS}

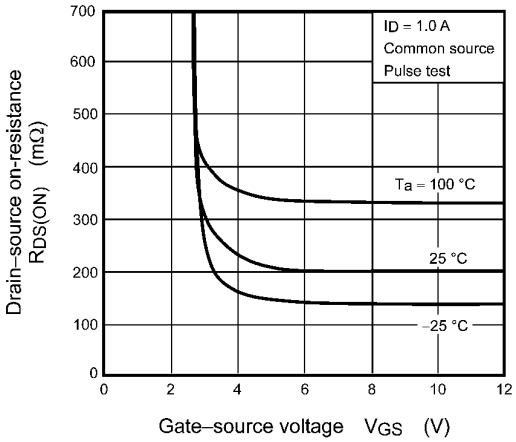


Fig. 7.3 $R_{DS(ON)}$ - V_{GS}

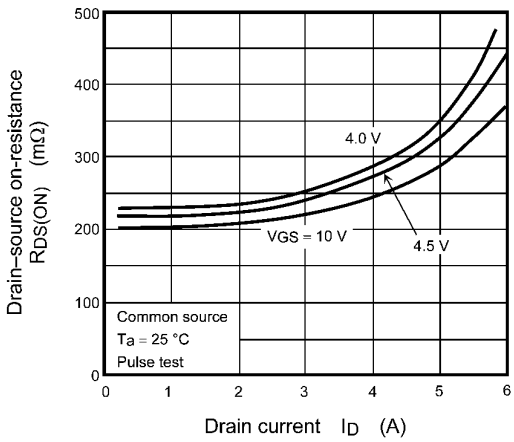


Fig. 7.4 $R_{DS(ON)}$ - I_D

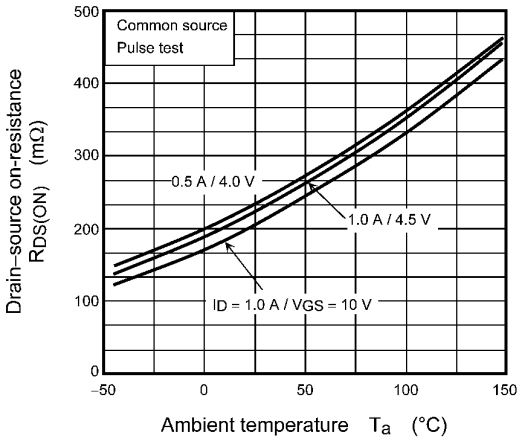


Fig. 7.5 $R_{DS(ON)}$ - T_a

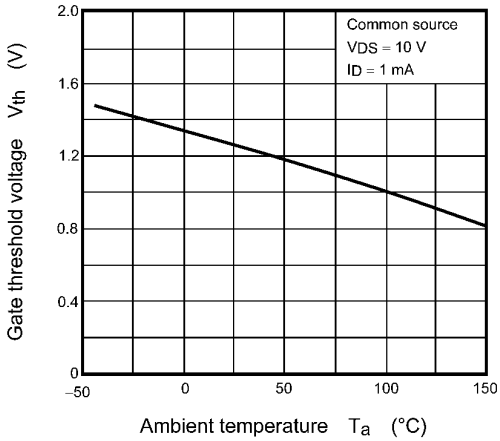


Fig. 7.6 V_{th} - T_a

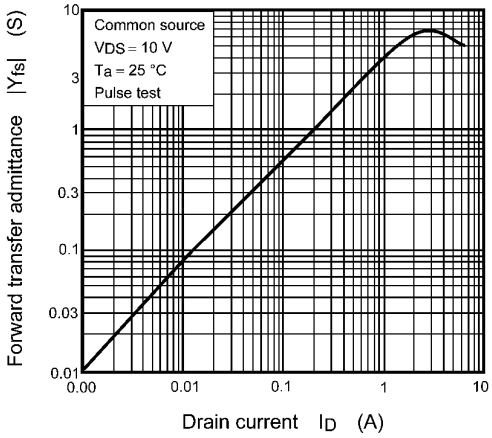


Fig. 7.7 $|Y_{fs}|$ - I_D

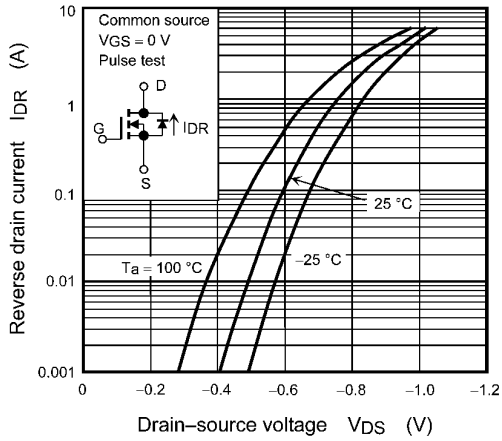


Fig. 7.8 I_{DR} - V_{DS}

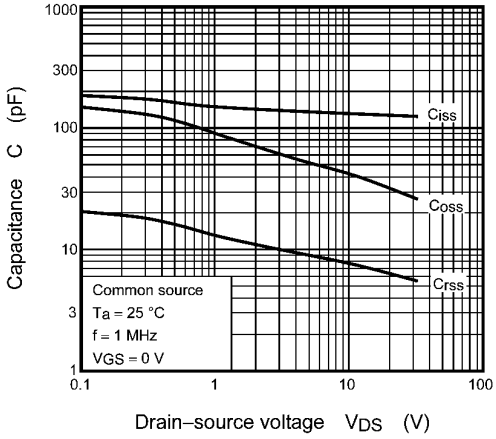


Fig. 7.9 C - V_{DS}

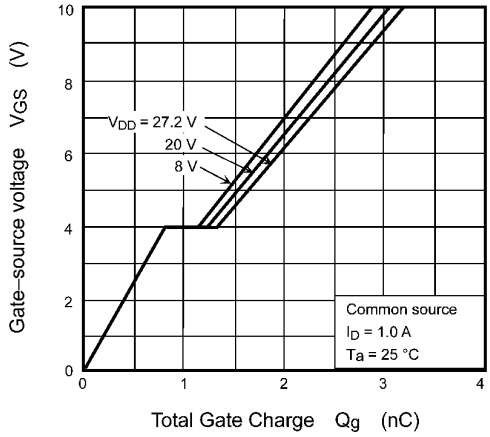


Fig. 7.10 Dynamic Input Characteristics

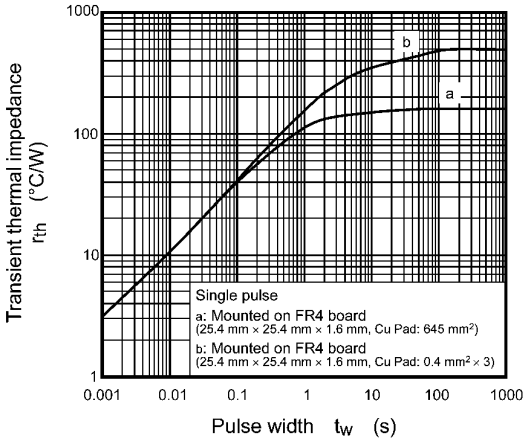


Fig. 7.11 r_{th} - t_w (MOSFET)

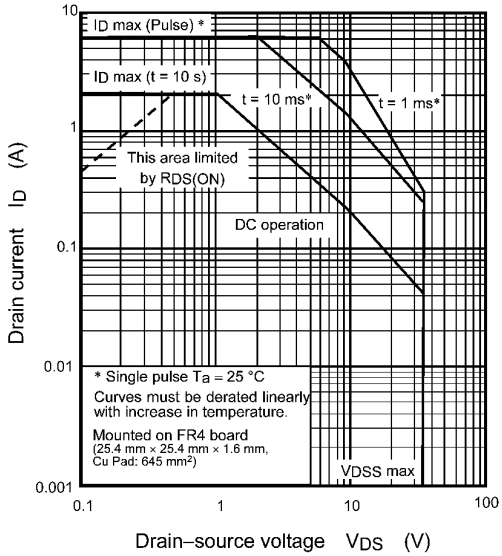


Fig. 7.12 Safe Operating Area

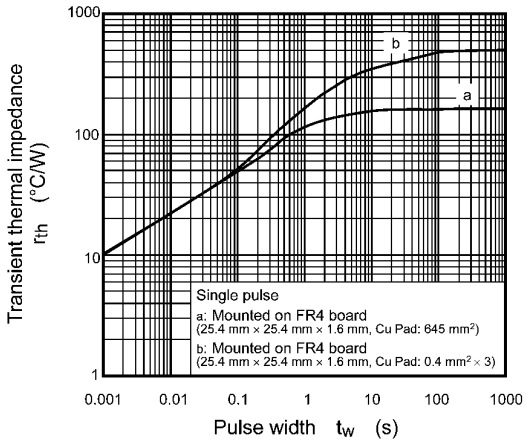


Fig. 7.13 r_{th} - t_w (Zener)

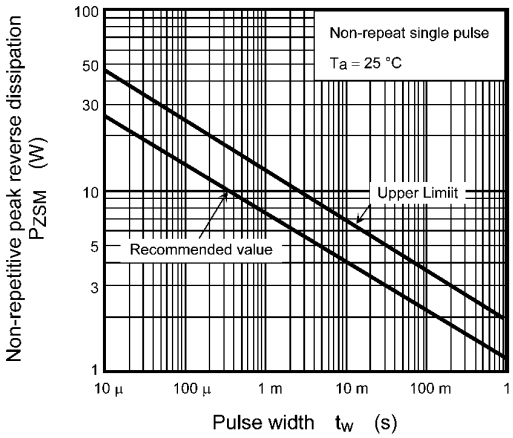
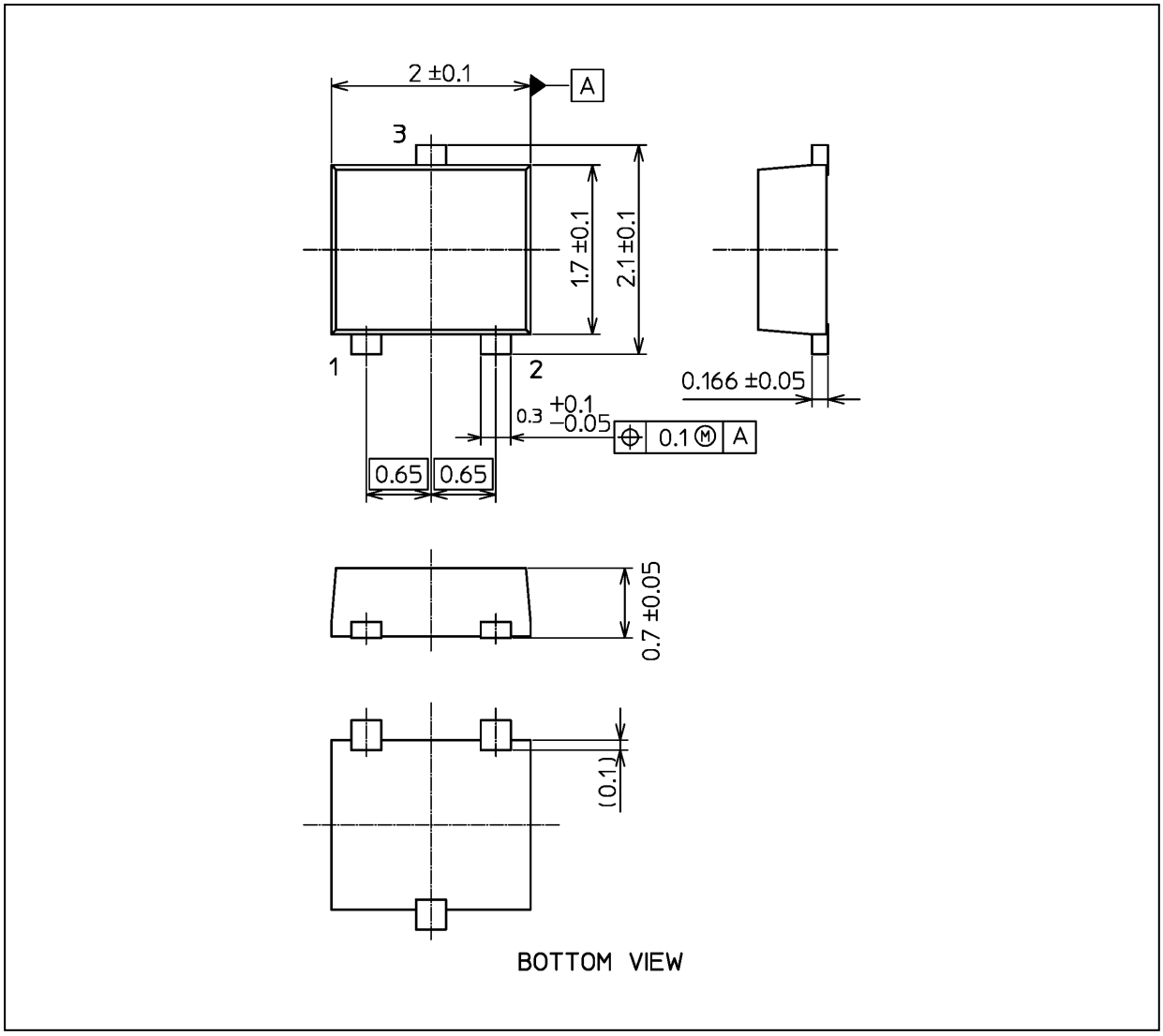


Fig. 7.14 P_{ZSM} - t

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Package Dimensions

Unit: mm



Weight: 6.6 mg (typ.)

Package Name(s)
Nickname: UFM

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